

# Reverse Monte Carlo Simulations and Raman Scattering of an Amorphous GeSe<sub>4</sub> Alloy Produced by Mechanical Alloying

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The short and intermediate range order of an amorphous GeSe<sub>4</sub> alloy produced by Mechanical Alloying were studied by Reverse Monte Carlo simulations of its x-ray total structure factor and Raman scattering. The simulations were used to compute the  $G_{\text{Ge-Ge}}^{\text{RMC}}(r)$ ,  $G_{\text{Ge-Se}}^{\text{RMC}}(r)$  and  $G_{\text{Se-Se}}^{\text{RMC}}(r)$  partial distribution functions and the  $S_{\text{Ge-Ge}}^{\text{RMC}}(K)$ ,  $S_{\text{Ge-Se}}^{\text{RMC}}(K)$  and  $S_{\text{Se-Se}}^{\text{RMC}}(K)$  partial structure factors. We calculated the coordination numbers and interatomic distances for the first and second neighbors and the bond-angle distribution functions  $\Theta_{ijl}(\cos \theta)$ . The data obtained indicate that the structure of the alloy has important differences when compared to alloys prepared by other techniques. There are a high number of Se-Se pairs in the first shell, and some of the tetrahedral units formed seemed to be connected by Se-Se bridges.

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## I. INTRODUCTION

Amorphous semiconductor materials like chalcogenide glasses present a great potential for application in technological devices, such as optical fibers, memory materials and switching devices, but their use is limited due to several factors. One of them is the difficulty in obtaining information about atomic structures, which define the short-range order (SRO) of the alloy. In this context, the structures of amorphous Ge<sub>x</sub>Se<sub>1-x</sub> (*a*-Ge<sub>x</sub>Se<sub>1-x</sub>) and liquid Ge<sub>x</sub>Se<sub>1-x</sub> (*l*-Ge<sub>x</sub>Se<sub>1-x</sub>), in particular Ge<sub>33</sub>Se<sub>67</sub> (GeSe<sub>2</sub>), have been extensively studied by several experimental techniques, like neutron diffraction (ND)<sup>1,2,3,4,5</sup>, x-ray diffraction (XRD)<sup>6,7</sup>, extended x-ray absorption fine structure (EXAFS)<sup>8,9</sup> and Raman spectroscopy (RS)<sup>10,11,12</sup>. On the theoretical side, molecular dynamics simulations (MD)<sup>13,14,15,16,17,18,19,20,21</sup> and reverse Monte Carlo (RMC) simulations<sup>7</sup> have been carried out to understand the SRO in these liquids and glasses in terms of two possible and distinct models. In the first one the distribution of bonds in the structure is purely random and determined by the local coordination numbers and composition. In the second one, there is a strong SRO and the structure is formed by well defined structural units, e.g., corner-sharing GeSe<sub>4/2</sub> (CS) tetrahedral and edge-sharing Ge<sub>2</sub>Se<sub>8/2</sub> (ES) bitetrahedral units. The distribution of these units gives raise to a medium, or intermediate, range order (IRO), whose signature is the appearance of a first sharp diffraction peak (FSDP) in the neutron<sup>1,3,4,5</sup> or x-ray structure factors<sup>6,7</sup> at many compositions. In particular, ND experiments performed on melt-quenched<sup>3,4,5</sup> (MQ) GeSe<sub>2</sub> (MQ-GeSe<sub>2</sub>) showed a FSDP in the total structure factor  $S(K)$  which was associated with correlations in the range of 5–6 Å. As described in Ref. 5, this alloy is formed by CS and ES units with heteropolar bonds but there are homopolar bonds in very small quantities. It should be noted, however, that almost all available data about *a*-Ge<sub>x</sub>Se<sub>1-x</sub> alloys were determined for MQ samples, and the preparation method can affect the SRO and IRO. We have recently verified this assumption in a study about the structure of *a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup> produced by Mechanical Alloying (MA)<sup>22</sup>. In our case, an unexpected large number of Se-Se pairs is found in the first coordination shell, suggesting that the tetrahedral units are linked by Se-Se “bridges”. Takeuchi *et al.*<sup>10</sup>, by comparing the structures of *a*-Ge<sub>30</sub>Se<sub>70</sub> produced by MQ and by vacuum evaporation (VE) techniques, and Tani *et al.*<sup>6</sup> studying the *a*-GeSe<sub>2</sub> produced by Mechanical Grinding (MG) of its crystalline counterpart have also found some structural differences among alloys produced by different methods. These differences are important because some physicochemical properties can be altered and improved as desired by choosing an appropriate preparation method.

In this paper, we investigated the SRO and IRO of an amorphous GeSe<sub>4</sub> alloy produced by MA (MA-*a*-GeSe<sub>4</sub>) starting from the elemental powders of Ge and Se using Raman spectroscopy (RS), X-ray diffraction and reverse Monte Carlo (RMC) simulations<sup>23,24,25,26</sup> of its XRD  $S(K)$ . We were interested in studying two main points. First of all we would like to know if the alloy produced by MA contains CS or ES units. Besides that, even if these units are formed the SRO and the IRO of the alloy can be significantly altered by the high quantity of defects and disorder introduced by the MA process when compared to MQ samples, for instance. Therefore, the second point is to determine the local structure of the alloy itself, finding coordination numbers and interatomic distances. At our knowledge, this is the first time that such study is reported concerning an *a*-GeSe<sub>4</sub> alloy produced by MA.

## II. THEORETICAL BACKGROUND

### A. Structure Factors

#### 1. Faber and Ziman structure factors

According to Faber and Ziman<sup>27</sup>, the total structure factor  $S(K)$  is obtained from the scattered intensity per atom  $I_a(K)$  through

$$\begin{aligned} S(K) &= \frac{I_a(K) - [\langle f^2(K) \rangle - \langle f(K) \rangle^2]}{\langle f(K) \rangle^2}, \\ &= \sum_{i=1}^n \sum_{j=1}^n w_{ij}(K) \mathcal{S}_{ij}(K), \end{aligned}$$

where  $K$  is the transferred momentum,  $\mathcal{S}_{ij}(K)$  are the partial structure factors and  $w_{ij}(K)$  are given by

$$w_{ij}(K) = \frac{c_i c_j f_i(K) f_j(K)}{\langle f(K) \rangle^2},$$

and

$$\begin{aligned} \langle f^2(K) \rangle &= \sum_i c_i f_i^2(K), \\ \langle f(K) \rangle^2 &= \left[ \sum_i c_i f_i(K) \right]^2. \end{aligned}$$

Here,  $f_i(K)$  is the atomic scattering factor and  $c_i$  is the concentration of atoms of type  $i$ . The partial reduced distribution functions  $G_{ij}(r)$  are related to  $\mathcal{S}_{ij}(K)$  through

$$G_{ij}(r) = \frac{2}{\pi} \int_0^\infty K [\mathcal{S}_{ij}(K) - 1] \sin(Kr) dK.$$

From the  $G_{ij}(r)$  functions the partial radial distribution function RDF $_{ij}(r)$  can be calculated by

$$\text{RDF}_{ij}(r) = 4\pi\rho_0 c_j r^2 + r G_{ij}(r).$$

where  $\rho_0$  is the density of the alloy (in atoms/Å<sup>3</sup>). Interatomic distances are obtained from the maxima of  $G_{ij}(r)$  and coordination numbers are calculated by integrating the peaks of RDF $_{ij}(r)$ .

#### 2. Bathia and Thornton structure factors

The Bathia-Thornton (BT) structure factors can be related to the FZ ones<sup>28</sup>. For a binary alloy the BT number-number structure factor  $\mathcal{S}_{\text{NN}}(K)$  is given by

$$\mathcal{S}_{\text{NN}}(K) = c_1^2 \mathcal{S}_{11}(K) + c_2^2 \mathcal{S}_{22}(K) + 2c_1 c_2 \mathcal{S}_{12}(K), \quad (1)$$

where  $\mathcal{S}_{ij}(K)$  are the FZ partial structure factors and  $c_i$  is the concentration of element  $i$ . The BT number-concentration structure factor  $\mathcal{S}_{\text{NC}}(K)$  is

$$\mathcal{S}_{\text{NC}}(K) = c_1 c_2 \left\{ c_1 [\mathcal{S}_{11}(K) - \mathcal{S}_{12}(K)] - c_2 [\mathcal{S}_{22}(K) - \mathcal{S}_{12}(K)] \right\}, \quad (2)$$

and the BT concentration-concentration structure factor  $\mathcal{S}_{\text{CC}}(K)$  is found through

$$\mathcal{S}_{\text{CC}}(K) = c_1 c_2 \left\{ 1 + c_1 c_2 [\mathcal{S}_{11}(K) + \mathcal{S}_{22}(K) - 2\mathcal{S}_{12}(K)] \right\}. \quad (3)$$

## B. RMC Method

The basic idea and the algorithm of the standard RMC method are described elsewhere<sup>23,24,25,26</sup> and its application to different materials is reported in the literature<sup>29,30,31,32,33,34,35,36,37,38,39,40,41</sup>. In the RMC procedure, a three-dimensional arrangement of atoms with the same density and chemical composition of the alloy is placed into a cell (usually cubic) with periodic boundary conditions and the  $G_{ij}^{\text{RMC}}(r)$  functions corresponding to it are directly calculated through

$$G_{ij}^{\text{RMC}}(r) = \frac{n_{ij}^{\text{RMC}}(r)}{4\pi\rho_0 r^2 \Delta r},$$

where  $n_{ij}^{\text{RMC}}(r)$  is the number of atoms at a distance between  $r$  and  $r + \Delta r$  from the central atom, averaged over all atoms. By allowing the atoms to move (one at each time) inside the cell, the  $G_{ij}^{\text{RMC}}(r)$  functions can be changed and, as a consequence,  $\mathcal{S}_{ij}^{\text{RMC}}(K)$  and  $\mathcal{S}^{\text{RMC}}(K)$  are changed. Thus,  $\mathcal{S}^{\text{RMC}}(K)$  is compared to the  $\mathcal{S}(K)$  factor in order to minimize the differences between them. The function to be minimized is

$$\psi^2 = \frac{1}{\delta} \sum_{i=1}^m [\mathcal{S}(K_i) - \mathcal{S}^{\text{RMC}}(K_i)]^2, \quad (4)$$

where the sum is over  $m$  experimental points and  $\delta$  is related to the experimental error in  $\mathcal{S}(K)$ . If the movement decreases  $\psi^2$ , it is always accepted. If it increases  $\psi^2$ , it is accepted with a probability given by  $\exp(-\Delta\psi^2/2)$ ; otherwise it is rejected. As this process is iterated  $\psi^2$  decreases until it reaches an equilibrium value. Thus, the atomic configuration corresponding to equilibrium should be consistent with the experimental total structure factor within the experimental error. By using the  $G_{ij}^{\text{RMC}}(r)$  functions the coordination numbers and interatomic distances can be calculated. In addition, the bond-angle distributions  $\Theta_{ijl}(\cos\theta)$  can also be determined.

## III. EXPERIMENTAL PROCEDURES

The MA-*a*-GeSe<sub>4</sub> alloy was produced by considering a binary mixture of high-purity elemental powders of germanium (Alfa Aesar 99.999% purity, particle size < 150  $\mu\text{m}$ ) and selenium (Alfa Aesar 99.999% purity, particle size < 150  $\mu\text{m}$ ) that was sealed together with several steel balls into a cylindrical steel vial under an argon atmosphere. The ball-to-powder weight ratio was 5:1. A Spex Mixer/Mill model 8000 was used to perform MA at room temperature. The mixture was continuously milled for 50 h. A ventilation system was used to keep the vial temperature close to room temperature. The XRD pattern was recorded in a powder Siemens diffractometer equipped with a graphite monochromator, using the  $\text{CuK}\alpha$  line ( $\lambda = 1.5418 \text{ \AA}$ ). The total structure factor  $\mathcal{S}(K)$  was computed from the XRD pattern after corrections for polarization, absorption, and inelastic scattering, following the procedure described by Wagner<sup>42</sup>. The  $f'$  and  $f''$  values were taken from a table compiled by Sasaki<sup>43</sup>. Raman measurements were performed with a T64000 Jobin-Yvon triple monochromator coupled to a cooled CCD detector and a conventional photon counting system. The 5145  $\text{\AA}$  line of an argon ion laser was used as exciting light, always in backscattering geometry. The output power of the laser was kept at about 200 mW to avoid overheating the samples. All Raman measurements were performed at room temperature.

## IV. RESULTS AND DISCUSSION

### A. Raman Scattering

Figure 1 shows the RS spectra of MA-*a*-GeSe<sub>4</sub>, *c*-Se and *c*-Ge. The alloy has bands at around 195, 215, 237 and 255  $\text{cm}^{-1}$ . The band at 195  $\text{cm}^{-1}$  is associated with the  $A_1$  breathing mode of CS units and the 215  $\text{cm}^{-1}$  band is related to the  $A_1^c$  breathinglike motions (companion peak) of Se in the ES units<sup>11,44,45</sup>. The difference in the intensities of these peaks indicates that the alloy is formed basically by CS tetrahedra and ES tetrahedra are found in a small quantity. The very weak shoulder around 237  $\text{cm}^{-1}$  is associated with  $A_1$  and  $E$  modes of Se chains, and they are also seen in *c*-Se (see Fig. 1). The broad and intense band at 255  $\text{cm}^{-1}$  is related to  $A_1$  and  $E_2$  modes of Se<sub>*n*</sub> rings<sup>8,10,44,45,46</sup>. It is important to note that the band at around 165  $\text{cm}^{-1}$ , which is associated with Ge-Ge pairs vibrations in ethanlike units, is not seen in the spectrum of the alloy (as well as the other bands of *c*-Ge), indicating

that the quantity of Ge-Ge pairs is very low in the alloy. In addition, the bands related to Se-Se pairs are not seen in the spectra of the alloys produced by MQ<sup>44</sup> or VE<sup>10</sup> techniques at this composition, but they exist in MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup> and in MA-*a*-GeSe<sub>4</sub>, and their intensities suggest that the number of Se-Se pairs in our alloy may be relevant. These results indicate that the tetrahedral units are formed during the MA process and there is a preference for CS units.

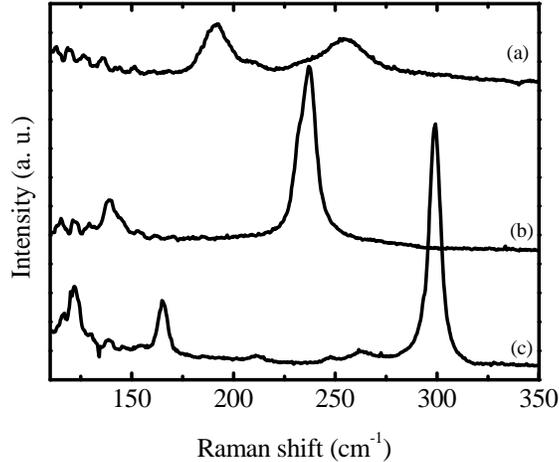


FIG. 1: RS spectra of (a) MA-*a*-GeSe<sub>4</sub>, (b) *c*-Se and (c) *c*-Ge.

## B. X-ray Diffraction and RMC Simulations

Figure 2 shows the experimental XRD  $\mathcal{S}(K)$  (full line) for our alloy and the experimental ND  $\mathcal{S}(K)$  (dashed line) given in Ref. 4 for MQ-*a*-GeSe<sub>4</sub>. The FSDP is seen at around  $1.1 \text{ \AA}^{-1}$ . It is lower than those shown in Refs. 4 and 1, indicating that the IRO in the alloy produced by MA is less pronounced than in the MQ-GeSe<sub>4</sub> samples<sup>1,4</sup>. The FSDP is known to be much dependent on Ge-Ge and, to a lesser extent, on Ge-Se correlations<sup>3,14,47,48</sup>. Therefore these correlations have a different behavior in MA-*a*-GeSe<sub>4</sub>. This fact is also verified in MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup>.

$\mathcal{S}(K)$  was simulated using the RMC program available on the Internet<sup>25</sup>. To perform the simulations we have considered a cubic cell with 16000 atoms (3200 Ge and 12800 Se),  $\delta = 0.002$ , and a mean atomic number density  $\rho_0 = 0.03834 \text{ atoms/\AA}^3$ . This value was found from the slope of the straight line ( $-4\pi\rho_0 r$ ) fitting the initial part (until the first minimum) of the total  $G(r)$  function<sup>49</sup>. The minimum distances between atoms were fixed at the beginning of the simulations at  $r_{\text{Ge-Ge}} = 2.0 \text{ \AA}$ ,  $r_{\text{Ge-Se}} = 1.8 \text{ \AA}$  and  $r_{\text{Se-Se}} = 1.7 \text{ \AA}$ . The  $\mathcal{S}^{\text{RMC}}(K)$  obtained from the simulations (squares) is also shown in Fig. 2 and there is a very good agreement with the experimental  $\mathcal{S}(K)$ .

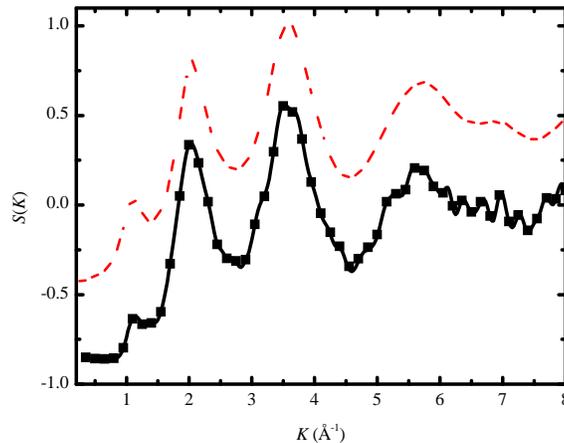


FIG. 2: Experimental (full line) and simulated (squares) total structure factor for MA-*a*-GeSe<sub>4</sub> together with the ND total structure factor given in Ref. 4 (dashed line) (for a better comparison it was cut at  $K_{\text{max}} = 8.0 \text{ \AA}^{-1}$ ).

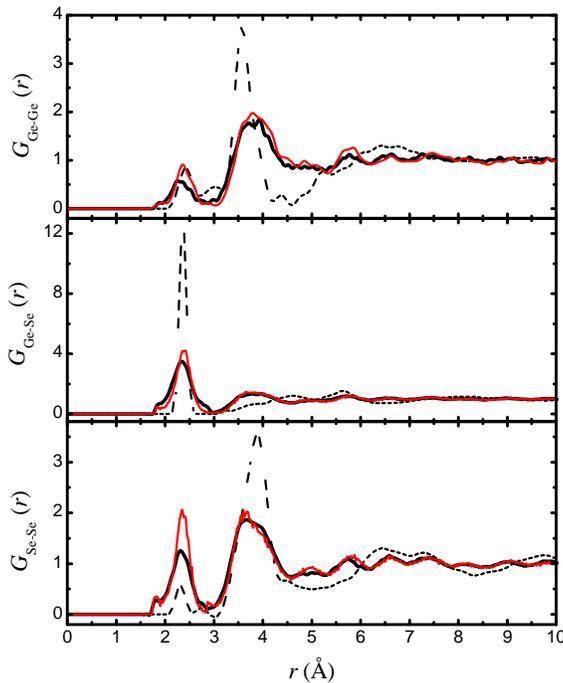


FIG. 3:  $G_{\text{Ge-Ge}}(r)$ ,  $G_{\text{Ge-Se}}(r)$  and  $G_{\text{Se-Se}}(r)$  functions obtained from RMC simulations of MA-*a*-GeSe<sub>4</sub> (thin solid lines) and MA-*a*-Ge<sub>30</sub>Se<sub>70</sub> (thick solid lines) and also the ND functions for MQ-GeSe<sub>2</sub> (dashed lines, Ref. 3).

First hard sphere simulations without experimental data were carried out to avoid possible memory effects of the initial configurations in the results. Then unconstrained runs (i.e. when only hard sphere diameters and experimental data were used during the simulation) were carried out. These runs led to essentially identical  $G_{ij}^{\text{RMC}}(r)$  functions, because of the proximity of the atomic numbers and scattering factors of Ge and Se. In the next series of simulations we used the coordination numbers we have found for MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup> as starting coordination constraints ( $N_{\text{Ge-Ge}} = 0.25$ ,  $N_{\text{Ge-Se}} = 3.5$  and  $N_{\text{Se-Se}} = 1.25$ ), which were then allowed to vary freely. The results obtained from the best simulation achieved are shown in Fig. 2 and they are discussed below. As a final test, we also tried to make simulations forcing the Se-Se coordination to be two, as it is in *a*-Se, but again the simulations did not show a good convergence. When this constraint is released, the Se-Se coordination number decreases until it reaches the number we found for the previous case ( $N_{\text{Se-Se}} = 1.71$ , see text below). This indicates that there are no amorphous or crystalline selenium in the mixture, and the Raman bands at 237 and 255 cm<sup>-1</sup> are associated with Se atoms that belong to the MA-*a*-GeSe<sub>4</sub> alloy.

### 1. Pair Distribution Functions

Figure 3 shows the  $G_{ij}^{\text{RMC}}(r)$  functions obtained from the RMC simulations of MA-*a*-GeSe<sub>4</sub> compared to those found experimentally for MQ-GeSe<sub>2</sub> using ND with isotopic substitution<sup>3</sup>. Since the  $G_{ij}(r)$  functions shown in Fig. 3 of Ref. 4 for MQ-GeSe<sub>4</sub> were calculated and their combination do not reproduce quite well the experimental  $G(r)$  function for this alloy, we have chosen not to compare our results with those functions. We have also added to Fig. 3 the  $G_{ij}^{\text{RMC}}(r)$  functions obtained for MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup> since it is interesting to compare both alloys produced by MA. The intensity of the first peak in  $G_{\text{Se-Se}}^{\text{RMC}}(r)$  is higher in the present alloy, confirming their existence in a larger quantity in the first coordination shell, as indicated by the RS measurement. The two first peaks of the  $G_{\text{Ge-Ge}}^{\text{RMC}}(r)$  function, which correspond to Ge-Ge first and second neighbors, show up around 2.35 and 3.80 Å. The first peak occurs at a distance a little shorter than that found in MQ-GeSe<sub>2</sub><sup>3,5</sup>, but the second is displaced towards higher- $r$  values by 0.23 Å. In addition, the peak at around 3.0 Å seen in MQ-GeSe<sub>2</sub> is not resolved in MA-*a*-GeSe<sub>4</sub>. Remembering that the distance between two Ge atoms in adjacent ES and CS units are found at 3.02 Å and 3.60 Å, respectively<sup>14,18</sup>, it can be seen that the fraction of ES units in MA-*a*-GeSe<sub>4</sub> is low, again in agreement with the results obtained by RS. Since the intensity of the FSDP in  $\mathcal{S}(K)$  seems to be related to the quantity of ES tetrahedra<sup>13,14,18,19</sup>, the low quantity of ES units in our alloy could explain the low intensity of the FSDP.

The first peak of  $G_{\text{Ge-Se}}^{\text{RMC}}(r)$  function is located at 2.36 Å. This shell in our alloy is lower and broader than in MQ-GeSe<sub>2</sub> but, due to the difference in densities, Ge-Se coordination numbers are almost the same in both alloys. The next peak appears at 3.84 Å, and it is higher than that at 4.95 Å. In the MQ-GeSe<sub>2</sub> samples, there is a peak around 3.02 Å which is not seen, or at least not resolved, in MA-*a*-GeSe<sub>4</sub>, and there are peaks at 3.78 Å (smaller) and 4.66 Å (higher). In *c*-GeSe<sub>2</sub> an ES Ge atom has Se neighbors in the range  $4.6 \lesssim r \lesssim 5.3$  Å, and a CS Ge atom has Se neighbors in the range  $4.0 \lesssim r \lesssim 4.8$  Å<sup>1,2</sup>. Then, we have associated the peak at 3.80 Å with CS units and that at 4.95 Å with CS and ES units.

The first peak of  $G_{\text{Se-Se}}^{\text{RMC}}(r)$  function is located at 2.33 Å, and it corresponds to a coordination number  $N_{\text{Se-Se}} = 1.71$ , which is much higher than that obtained for the MQ-GeSe<sub>2</sub> samples ( $N_{\text{Se-Se}} = 0.20$ )<sup>3,5</sup>. This suggests that some of the tetrahedral units are connected by Se “bridges”, forming sequences such as Ge-Se-Se-Se-Ge. As a consequence, Ge-Ge pairs should be found at higher distance values. This agrees with the results obtained from the  $G_{\text{Ge-Ge}}^{\text{RMC}}(r)$  function. The next peak appears at 3.75 Å, which gives a ratio of Ge-Se:Se-Se distances of 0.632. The value expected for ideal tetrahedral coordination is  $\sqrt{3}/8 = 0.612$ , indicating that the tetrahedral (CS or ES) units are distorted in our alloy. It is interesting to note that in MQ-GeSe<sub>2</sub> samples no peaks are found from  $\approx 4.5$  Å to  $\approx 5.9$  Å either considering ND results<sup>3,5</sup> or MD simulations<sup>14,20</sup>. On the other hand, in MA-*a*-GeSe<sub>4</sub> there are peaks at 4.95 and 5.75 Å, and we believe these peaks are related to the distances between Se atoms in the “bridges” and Se atoms in tetrahedral units. These features were also found in MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup>. The peaks at around 6.6 and 7.4 Å, which are also seen in MQ-GeSe<sub>2</sub> samples, can be associated, following Ref. 14, to distances between Se atoms belonging to two adjacent tetrahedral units.

The coordination numbers show in Table I were calculated considering the  $\text{RDF}_{ij}^{\text{RMC}}(r)$  functions shown in Fig. 4. The integrations were made using the following ranges: from 1.7 Å to 2.95 Å to the first peak and from 2.95 Å to 4.5 Å to the second peak, for all  $\text{RDF}_{ij}^{\text{RMC}}(r)$  functions. The interatomic distances are also shown in Table I. For a comparison, Fig. 4 also shows the  $\text{RDF}_{ij}^{\text{RMC}}(r)$  functions for MA-*a*-Ge<sub>30</sub>Se<sub>70</sub>, and its structural data are also shown in Table I. It is interesting to note that except for Ge-Ge pairs, coordination numbers are always larger in MA-*a*-GeSe<sub>4</sub> than in MA-*a*-Ge<sub>30</sub>Se<sub>70</sub>. If we compare our results with those found by MD simulations of *l*-GeSe<sub>4</sub><sup>21</sup>, in which it is found  $N_{\text{Ge-Ge}} = 0.06$ ,  $N_{\text{Ge-Se}} = 3.87$  and  $N_{\text{Se-Se}} = 1.04$ , a large increase in the homopolar coordination numbers is seen, suggesting that the liquid and the amorphous alloy produced by MA have important differences from the structural point of view. This was also verified in an amorphous Ga<sub>50</sub>Se<sub>50</sub> alloy produced by MA studied recently by us<sup>50</sup>.

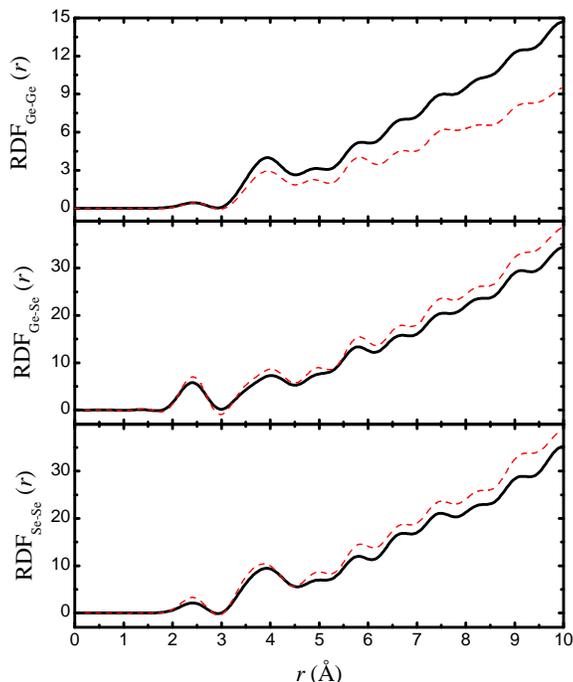


FIG. 4:  $\text{RDF}_{\text{Ge-Ge}}^{\text{RMC}}(r)$ ,  $\text{RDF}_{\text{Ge-Se}}^{\text{RMC}}(r)$  and  $\text{RDF}_{\text{Se-Se}}^{\text{RMC}}(r)$  obtained from the RMC simulations for MA-*a*-GeSe<sub>4</sub> (dashed lines) and MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup> (solid lines).

TABLE I: Structural Parameters obtained for MA-*a*-GeSe<sub>4</sub>.

RMC								
First Shell					Second Shell			
Bond Type	Ge-Ge	Ge-Se	Se-Ge	Se-Se	Ge-Ge	Ge-Se	Se-Ge	Se-Se
$N$	0.22	3.61	0.90	1.71	2.70	8.3	2.1	10.1
$r$ (Å)	2.35	2.36	2.36	2.33	3.80	3.84	3.84	3.75
MA- <i>a</i> -Ge <sub>30</sub> Se <sub>70</sub> <sup>7</sup>								
Bond Type	Ge-Ge	Ge-Se	Se-Ge	Se-Se	Ge-Ge	Ge-Se	Se-Ge	Se-Se
$N$	0.26	3.50	1.75	1.25	3.85	7.4	3.7	9.7
$r$ (Å)	2.33	2.35	2.35	2.33	3.83	3.84	3.84	3.75
MQ-GeSe <sub>2</sub> studied by ND <sup>3,5</sup>								
Bond Type	Ge-Ge	Ge-Se	Se-Ge	Se-Se	Ge-Ge	Ge-Se <sup>a</sup>	Se-Ge <sup>a</sup>	Se-Se
$N$	0.25	3.7	1.8	0.20	3.2	-	-	9.3
$r$ (Å)	2.42	2.36	2.36	2.32	3.57	-	-	3.89
<i>l</i> -GeSe <sub>2</sub> studied by ND <sup>2</sup>								
Bond Type	Ge-Ge	Ge-Se	Se-Ge	Se-Se	Ge-Ge	Ge-Se	Se-Ge	Se-Se
$N$	0.25	3.5	1.7	0.23	2.9	4.0	2.0	9.6
$r$ (Å)	2.33	2.42	2.42	2.30	3.59	4.15	4.15	3.75

<sup>a</sup>These numbers are not given in Refs. 3 or 5 due to the difficulty in defining the second shell.

## 2. Partial Structure Factors

The partial  $\mathcal{S}_{ij}^{\text{RMC}}(K)$  are shown in Fig. 5, together with the  $\mathcal{S}_{ij}^{\text{ND}}(K)$  found in Ref. 3 and also with the  $\mathcal{S}_{ij}^{\text{RMC}}(K)$  for MA-*a*-Ge<sub>30</sub>Se<sub>70</sub><sup>7</sup>.  $\mathcal{S}_{\text{Ge-Ge}}^{\text{RMC}}(K)$  has its first three peaks at about 1.1 (very weak), 1.9 and 3.4 Å<sup>-1</sup> and two minima at 1.2 and 2.8 Å<sup>-1</sup>. Their positions agree reasonably well with those found for MQ-GeSe<sub>2</sub> studied by ND<sup>3,5</sup>, but intensities are very different. The first peak is lower in MA-*a*-Ge<sub>30</sub>Se<sub>70</sub> and almost unresolved in MA-*a*-GeSe<sub>4</sub>. This peak is associated with the FSDP in the  $\mathcal{S}(K)$  shown in Fig. 2 and, since the FSDP is known to be strongly dependent on the Ge-Ge correlations and, to a lesser extent, on the Ge-Se correlations<sup>14,47,48</sup>, the low intensity FSDP experimentally observed in Fig. 2 could be caused by weak Ge-Ge and Ge-Se correlations at its position. In addition, the heights of the second and third peaks are almost the same, and in MQ samples the height of the second peak is twice of that of the third peak.

$\mathcal{S}_{\text{Ge-Se}}^{\text{RMC}}(K)$  has two maxima at 1.1 and 3.5 Å<sup>-1</sup> and a minimum at 1.7 Å<sup>-1</sup>. Again, the first peak of MA-*a*-GeSe<sub>4</sub> is lower than that found in MQ-GeSe<sub>2</sub> samples, but its position is the same, and it is also associated with the FSDP in  $\mathcal{S}(K)$ . The second peak and the first minimum in MQ samples are found at 3.5 Å<sup>-1</sup> and 2.1 Å<sup>-1</sup>, respectively, indicating that in our alloy they are dislocated to higher (the maxima) and lower- $K$  (the minimum) values. These facts can be explained by the important differences between the  $G_{\text{Ge-Se}}^{\text{RMC}}(r)$  function and that of the MQ samples for  $r > 4$  Å.

$\mathcal{S}_{\text{Se-Se}}^{\text{RMC}}(K)$  has two peaks at around 2.0 and 3.6 Å<sup>-1</sup>, and there is a minimum at 2.8 Å<sup>-1</sup>. At about 1.2 Å<sup>-1</sup> there is a small peak associated with the FSDP in  $\mathcal{S}(K)$ . In MQ-GeSe<sub>2</sub> samples the peaks are seen at 0.95, 2.05 and 3.55 Å<sup>-1</sup>, and there is a minimum at 2.75 Å<sup>-1</sup>. These data indicate that  $\mathcal{S}_{\text{Se-Se}}^{\text{RMC}}(K)$  is similar to that of MQ-GeSe<sub>2</sub> samples, at least in the low- $K$  region, concerning peak positions. However, we should note that their heights are different, in particular the intensity of the peak at 2.0 Å<sup>-1</sup>.

It is important to compare our results considering the BT formalism. Figure 6 shows the  $\mathcal{S}_{\text{NN}}^{\text{RMC}}(K)$ ,  $\mathcal{S}_{\text{NC}}^{\text{RMC}}(K)$  and  $\mathcal{S}_{\text{CC}}^{\text{RMC}}(K)$  factors obtained using Eqs. 1, 2 and 3, together with those factors found by ND and shown in Ref. 3. As expected,  $\mathcal{S}_{\text{NN}}^{\text{RMC}}(K)$  resembles the XRD  $\mathcal{S}(K)$  because the scattering lengths of Ge and Se are almost the same, and it is very similar to the  $\mathcal{S}_{\text{NN}}^{\text{ND}}(K)$  found for MQ-GeSe<sub>2</sub>, except for the FSDP intensity at 1.0 Å<sup>-1</sup>. Although there are differences in the peak intensities,  $\mathcal{S}_{\text{NC}}^{\text{RMC}}(K)$  resembles that found for *l*-GeSe<sub>2</sub><sup>2,15,16,51</sup> and for MQ-GeSe<sub>2</sub><sup>3</sup>, including the sharp minimum at 2.0 Å<sup>-1</sup>.  $\mathcal{S}_{\text{CC}}(K)$  also behaves like that obtained for *l*-GeSe<sub>2</sub><sup>2,51</sup> and MQ-GeSe<sub>2</sub><sup>3</sup>. In *l*-GeSe<sub>2</sub> a sharp FSDP is clearly seen in  $\mathcal{S}_{\text{CC}}(K)$  at around 1.0 Å<sup>-1</sup>, and this fact also occurs in MQ-GeSe<sub>2</sub> samples. MD simulations of *l*-GeSe<sub>2</sub><sup>15,16</sup> and MQ-GeSe<sub>2</sub><sup>20</sup> could not reproduce well this peak. In our case, a very weak FSDP can be seen at 1.1 Å<sup>-1</sup> as a shoulder of the high peak at 2.0 Å<sup>-1</sup>. Remembering that the FSDP in  $\mathcal{S}(K)$  (see Fig. 2) has a low intensity and considering all the results discussed above, we should not expect that the FSDP in  $\mathcal{S}_{\text{CC}}(K)$  was

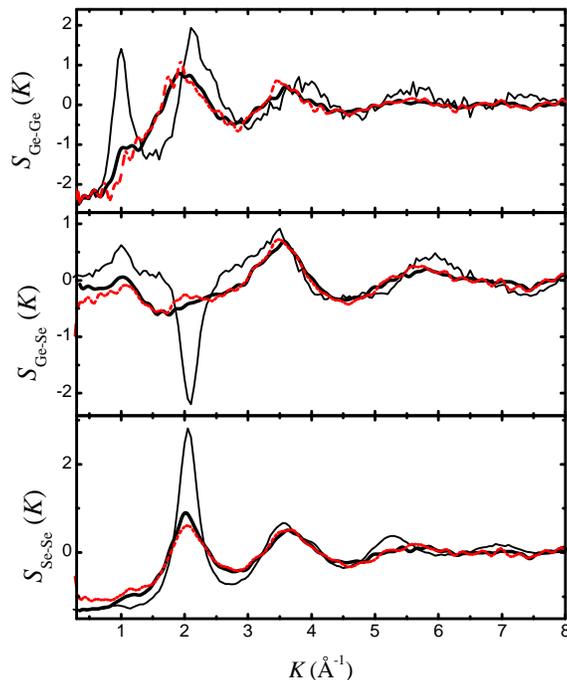


FIG. 5:  $S_{\text{Ge-Ge}}(K)$ ,  $S_{\text{Ge-Se}}(K)$  and  $S_{\text{Se-Se}}(K)$  factors obtained from the RMC simulations for MA-*a*-GeSe<sub>4</sub> (dashed lines) and MA-*a*-Ge<sub>30</sub>Se<sub>70</sub> (thick solid lines), and also the ND  $S_{ij}(K)$  of MQ-GeSe<sub>2</sub> (thin solid lines, Ref. 3).

as high and well defined as it is in *l*- or MQ-GeSe<sub>2</sub> samples. The IRO in MA-*a*-GeSe<sub>4</sub> is different mainly because of the introduction of Se-Se first neighbor pairs as “bridges” between the tetrahedral units, thus decreasing the number of ES units and increasing the number of CS units. This affects the short and medium range order, which, in its turn, changes the concentration-concentration BT factor.

### 3. Bond-Angle Distribution Functions

By defining the partial bond-angle distribution functions  $\Theta_{ijl}(\cos\theta)$  where *j* is the atom in the corner we calculated the angular distribution of the bonds between first neighbor atoms. The six  $\Theta_{ijl}(\cos\theta)$  functions are shown in Fig. 7. All these functions were calculated considering as  $r_{\text{max}}$  the position of the first minimum after the peak of the first shell ( $r_{\text{max}} \approx 3.0 \text{ \AA}$ ).

The  $\Theta_{\text{Ge-Ge-Ge}}(\cos\theta)$  function is very noisy because of the very small number of Ge-Ge pairs in the first shell, but it shows a tendency for angles around 100°. The  $\Theta_{\text{Se-Se-Se}}(\cos\theta)$  function has peaks at 55–61° and a broad distribution from 99 to 118°, with a maximum at 103°. The internal Se-Se-Se angles in perfect tetrahedra are found at 60°, the Se-Se-Se angle in trigonal Se is seen at 103° and the angles in small Se chains and rings<sup>46</sup> can be found at 90–116°. Thus, the  $\Theta_{\text{Se-Se-Se}}(\cos\theta)$  function indicates that the tetrahedra in MA-*a*-GeSe<sub>4</sub> are slightly distorted and Se chains and rings are formed, in agreement with RS results and with the previous analyses of the  $G_{ij}(r)$  functions. The  $\Theta_{\text{Se-Ge-Se}}(\cos\theta)$  function is very similar to the  $\Theta_{\text{Se-Se-Se}}(\cos\theta)$  function, showing peaks at 58° and 105°, which is close to the ideal tetrahedral angle of 109°.

The  $\Theta_{\text{Ge-Se-Ge}}(\cos\theta)$  function peaks at about 58° and 106°. The Ge-Se-Ge sequence in ES units has angles around 80° that are not seen in this function, reinforcing the small quantity of these units. On the other hand, this sequence in CS units has angles around 100°, and *n*-fold rings have angles ranging from 92° to 125°. The  $\Theta_{\text{Se-Ge-Ge}}(\cos\theta)$  and  $\Theta_{\text{Ge-Se-Se}}(\cos\theta)$  functions are similar to the others, having peaks at 58°, associated with threefold rings, and at 116° (Se-Ge-Ge) and 109° (Ge-Se-Se), which are related to tetrahedral angles and *n*-fold rings. The  $\Theta_{ijl}(\cos\theta)$  functions above confirm that distorted tetrahedral units are formed in MA-*a*-GeSe<sub>4</sub>, with a clear preference for CS units. These units seem to be connected by Se-Se bridges, forming small chains and rings, as pointed out by the RS data.

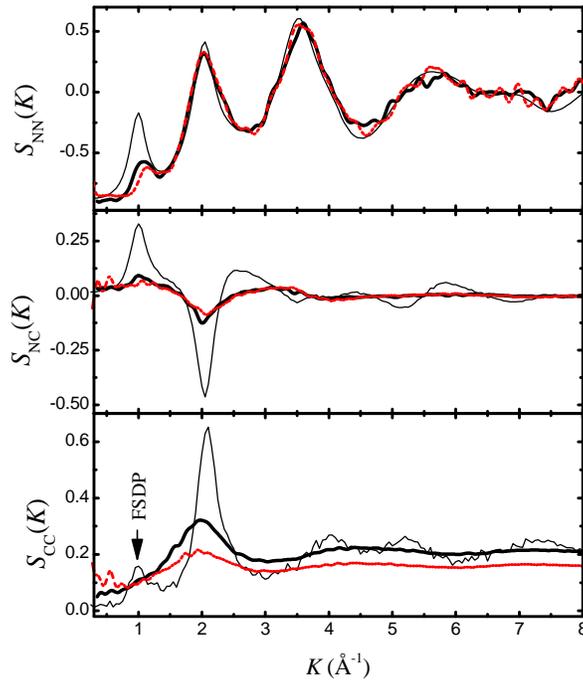


FIG. 6: Bathia-Thornton  $\mathcal{S}_{NN}(K)$ ,  $\mathcal{S}_{NC}(K)$  and  $\mathcal{S}_{CC}(K)$  factors obtained from RMC simulations for MA- $a$ -GeSe<sub>4</sub> (dashed lines) and MA- $a$ -Ge<sub>30</sub>Se<sub>70</sub> (thick solid lines) and also the ND BT structure factors of MQ-GeSe<sub>2</sub> (thin solid lines, Ref. 3). The arrow indicates the FSDP in  $\mathcal{S}_{CC}^{\text{RMC}}(K)$ .

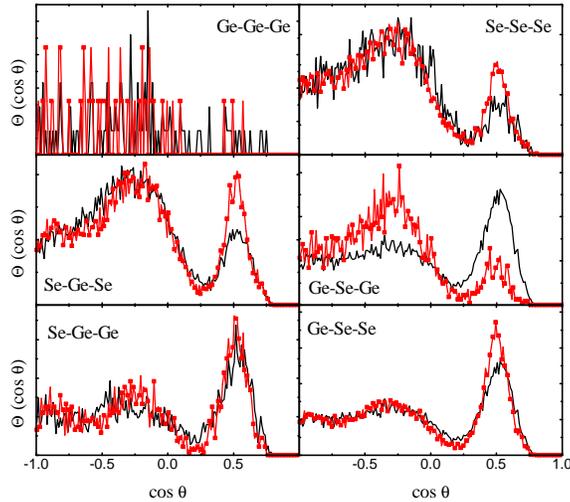


FIG. 7:  $\Theta_{ijl}(\cos \theta)$  functions obtained from RMC simulations for MA- $a$ -GeSe<sub>4</sub> (squared line) and MA- $a$ -Ge<sub>30</sub>Se<sub>70</sub> (solid line).

## V. CONCLUSION

To summarize, we can conclude that the amorphous GeSe<sub>4</sub> alloy can be produced by MA starting from the elemental powders of Ge and Se, but the structure of the alloy is different from that found in MQ-, VE- or MG-GeSe<sub>2</sub> or MQ-GeSe<sub>4</sub> samples, making clear the importance of the preparation technique. Structural units similar to distorted CS and ES tetrahedra are formed, with a preference for CS tetrahedra, as indicated by Raman spectroscopy. These units seem to be connected by Se-Se bridges, as suggested by the high number of these pairs in the first shell, by the increase in the distance between Ge-Ge second neighbors, by the  $\Theta_{ijl}(\cos \theta)$  functions and also by RS vibrational data. These differences in the SRO affect the IRO of the alloy, and this causes the low intensity of the FSDP in  $\mathcal{S}(K)$  of MA- $a$ -GeSe<sub>4</sub> when compared to the MQ-GeSe<sub>4</sub> alloy<sup>4</sup>. The low intensity of the FSDP in  $\mathcal{S}(K)$  can be traced back to

the partial  $\mathcal{S}_{\text{Ge-Ge}}(K)$  factor, whose FSDP is related to the ES units, which are found in a small quantity in the alloy.  $\mathcal{S}_{\text{CC}}(K)$  reflects these features and shows a very weak FSDP when compared to the factor found for  $l\text{-GeSe}_2$ <sup>2,15,16</sup> or MQ-GeSe<sub>2</sub><sup>3</sup>.

As a second remark, this study reinforces the relevance of using and combining RMC simulations with other techniques to model amorphous structures, since all features described above were obtained considering directly the experimental  $\mathcal{S}(K)$  in the simulations.

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